

Silicon photonic devices and integrated circuits

Po Dong*, Young-Kai Chen, Guang-Hua Duan and David T. Neilson Nanophotonics 3.4-5 (2014): 215-228.

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Introduction

- ✤ Definition of Silicon Photonic devices in this paper
 - 1. Using silicon-core waveguide
 - ✓ High index contrast (≈ 2) with silicon oxide as a cladding
 - ✓ High density integration (sub-micrometer)
 - ✓ High coupling efficiency between silicon waveguide and optical fiber



- 2. Whole-wafer processing based on CMOS fabrication
 - ✓ Large-scale & low-cost manufacturability.
 - ✓ Monolithic integration of silicon PICs with CMOS drivers
 - ✓ Solve interconnect bottlenecks of modern electronic ICs





Introduction

- Applications
 - 1. Long-haul/metro coherent optical networks
 - > High-order modulation (QAM, OFDM) and coherent detection
 - > Maximize channel capacity up to 100 Gb/s, 400 Gb/s, 1 Tb/s
 - > Integration of complex photonic circuit and CMOS electronics



< Optical coherent transmitter >



< Optical coherent receiver >

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Introduction

- Applications
 - 2. Optical interconnects for routers and switches
 - 3. Datacenters and supercomputers
 - ✓ Low power consumption & Co-integration of electronics and photonics







WDM transmitters & receivers

WDM (Wavelength Division Multiplexing)



< Basic WDM technology diagram >

- Multi-channel system
- Transport multiple wavelengths over a fiber
- Use wavelength Mux/Demux



< AWG (Arrayed Waveguide Gratings) >

- Widely used for optical MUX/DeMUX
- Composed of two couplers and waveguides array
- Use phase shift and optical interference





WDM transmitters & receivers

WDM transmitter (100 GHz spacing, 25 Gbps/wavelength, 5x8 mm² footprint)







WDM transmitters & receivers

WDM receiver (0.2 A/W, 200 GHz spacing, 40 channels)



Monolithically integrated WDM receiver



< cantilever based spot-size converter >

Component	Waveguide	Reason
Spot-size converter	Si ₃ N ₄	Low coupling loss
AWG	Si ₃ N ₄	Fabrication tolerance
Waveguides	Silicon	Low loss
Ge-PD	Silicon	p-n junctions





✤ Optical coherent system

- High spectral efficiency: High-order modulation (QAM, OFDM)
- High receiver sensitivity: optical beating between signal and local oscillator





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✤ Optical coherent system

- High spectral efficiency: High-order modulation (QAM, OFDM)
- ▶ High receiver sensitivity: optical beating between signal and local oscillator



- ✤ Coherent transmitter
 - > MZM based dual-polarization coherent transmitter (PDM-IQ modulator)







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- ✤ Coherent transmitter
 - Ring modulator based coherent transmitter



< BPSK modulation in ring modulator >



< QPSK modulator based on ring modulator >

- > BPSK modulation using overdrive of ring modulator
- BPSK modulator x 2 + phase shift = QPSK modulator





- Coherent receiver
 - Dual-polarization coherent receiver (PDM-coherent receiver)



IT: inverse taper, **LO**: local oscillator, **PBS**: polarization beam splitter, **MMI**: multimode interference coupler (90 degree hybrid)

> Components

- ✓ Two PBSs
- ✓ Two ITs
- ✓ Two PRs
- ✓ Two MMIs
- ✓ Eight PDs













Summary

- Silicon Photonic devices
 - Using silicon-core waveguide
 - Whole-wafer processing based on CMOS fabrication
 - > Applications
 - ✓ Long-haul/metro coherent optical networks
 - ✓ Optical interconnects for routers and switches
 - ✓ Datacenters and supercomputers
 - > PICs
 - ✓ WDM transmitter/receiver
 - Integration of AWG and modulators array/PDs array
 - ✓ Coherent transmitter & receiver
 - MZM based PDM-IQ modulator
 - Micro-ring modulator based Coherent transmitter
 - PDM-coherent receiver



